

DATA SHEET



BAV105 High-speed diode

Product specification
Supersedes data of April 1996

1996 Sep 17

High-speed diode

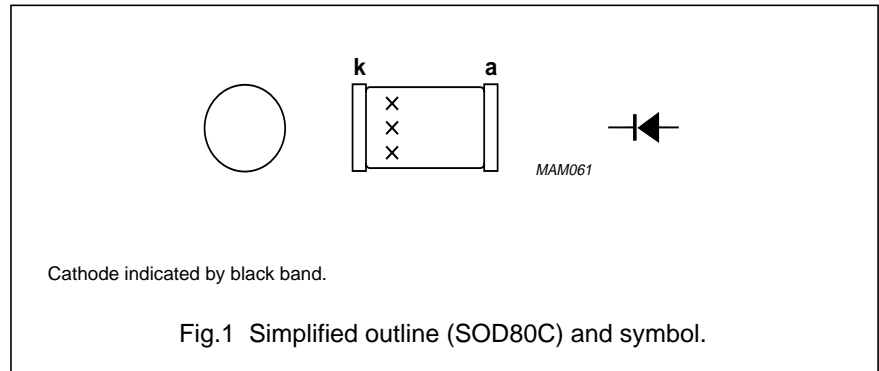
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FEATURES

- Small hermetically sealed glass SMD package
- High switching speed: max. 6 ns
- General application
- Continuous reverse voltage: max. 60 V
- Repetitive peak reverse voltage: max. 60 V
- Repetitive peak forward current: max. 600 mA.

DESCRIPTION

The BAV105 is a high-speed switching diode fabricated in planar technology, and encapsulated in the small hermetically sealed glass SOD80C SMD package.



APPLICATIONS

- High-speed switching in e.g. surface mounted circuits.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-----------|-------------------------------------|--|-------------|-------------|-------------|
| V_{RRM} | repetitive peak reverse voltage | | – | 60 | V |
| V_R | continuous reverse voltage | | – | 60 | V |
| I_F | continuous forward current | see Fig.2; note 1 | – | 300 | mA |
| I_{FRM} | repetitive peak forward current | | – | 600 | mA |
| I_{FSM} | non-repetitive peak forward current | square wave; $T_j = 25\text{ °C}$ prior to surge; see Fig.4 $t = 1\ \mu\text{s}$ $t = 100\ \mu\text{s}$ $t = 1\ \text{s}$ | – – – | 9 3 1 | A A A |
| P_{tot} | total power dissipation | $T_{amb} = 25\text{ °C}$; note 1 | – | 500 | mW |
| T_{stg} | storage temperature | | –65 | +200 | °C |
| T_j | junction temperature | | – | 200 | °C |

Note

1. Device mounted on an FR4 printed-circuit board.

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ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ °C}$; unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|----------|--------------------------|---|------|------|---------------|
| V_F | forward voltage | see Fig.3 | | | |
| | | $I_F = 10\text{ mA}$ | – | 750 | mV |
| | | $I_F = 200\text{ mA}$ | – | 1000 | mV |
| | | $I_F = 500\text{ mA}$ | – | 1.25 | V |
| | | $I_F = 200\text{ mA}; T_j = 100\text{ °C}$ | – | 950 | mV |
| I_R | reverse current | see Fig.5 | | | |
| | | $V_R = 60\text{ V}$ | – | 100 | nA |
| | | $V_R = 60\text{ V}; T_j = 150\text{ °C}$ | – | 100 | μA |
| C_d | diode capacitance | $f = 1\text{ MHz}; V_R = 0$; see Fig.6 | – | 2.5 | pF |
| t_{rr} | reverse recovery time | when switched from $I_F = 400\text{ mA}$ to $I_R = 400\text{ mA}; R_L = 100\ \Omega$; measured at $I_R = 40\text{ mA}$; see Fig.7 | – | 6 | ns |
| V_{fr} | forward recovery voltage | when switched from $I_F = 400\text{ mA}$; $t_{r1} = 30\text{ ns}$; see Fig.8 | – | 2 | V |
| | | when switched from $I_F = 400\text{ mA}$; $t_{r2} = 100\text{ ns}$; see Fig.8 | – | 1.5 | V |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------|---|------------|-------|------|
| $R_{th\ j-tp}$ | thermal resistance from junction to tie-point | | 300 | K/W |
| $R_{th\ j-a}$ | thermal resistance from junction to ambient | note 1 | 350 | K/W |

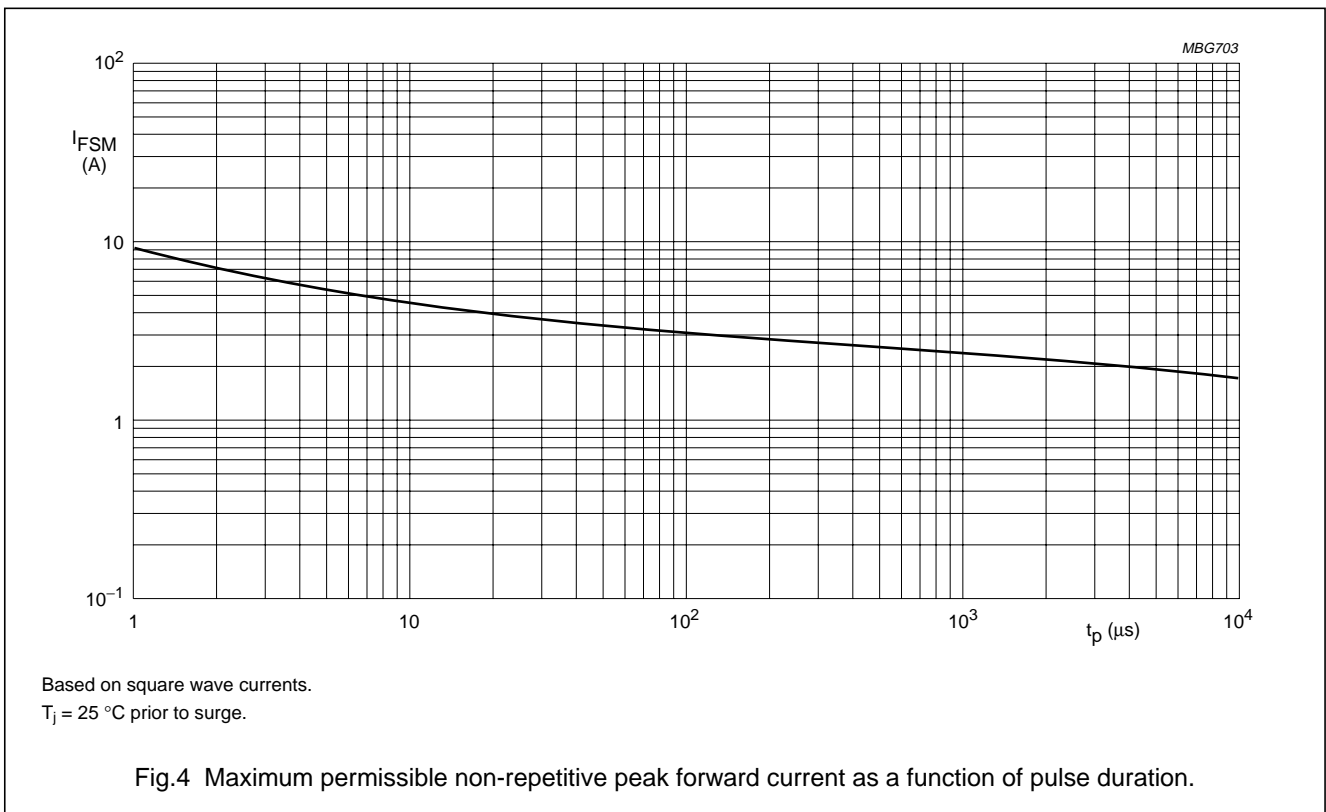
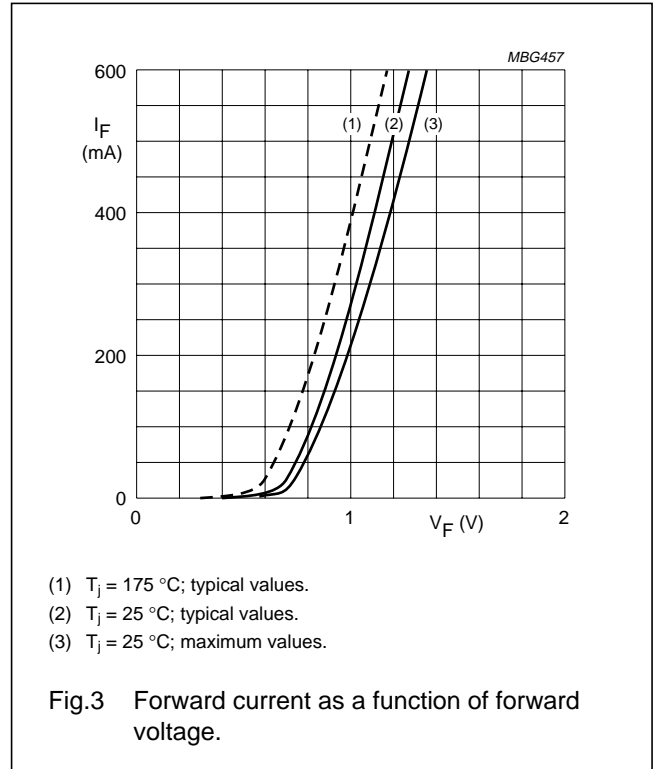
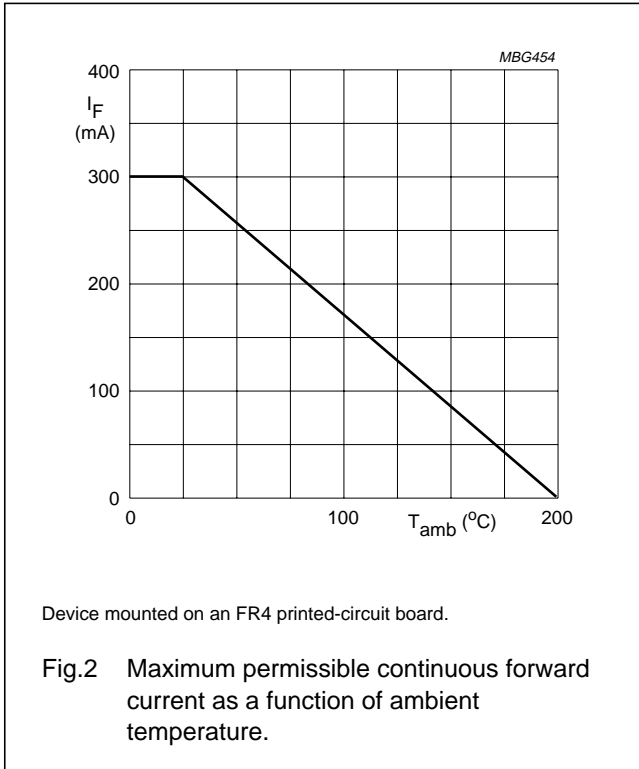
Note

1. Device mounted on an FR4 printed-circuit board.

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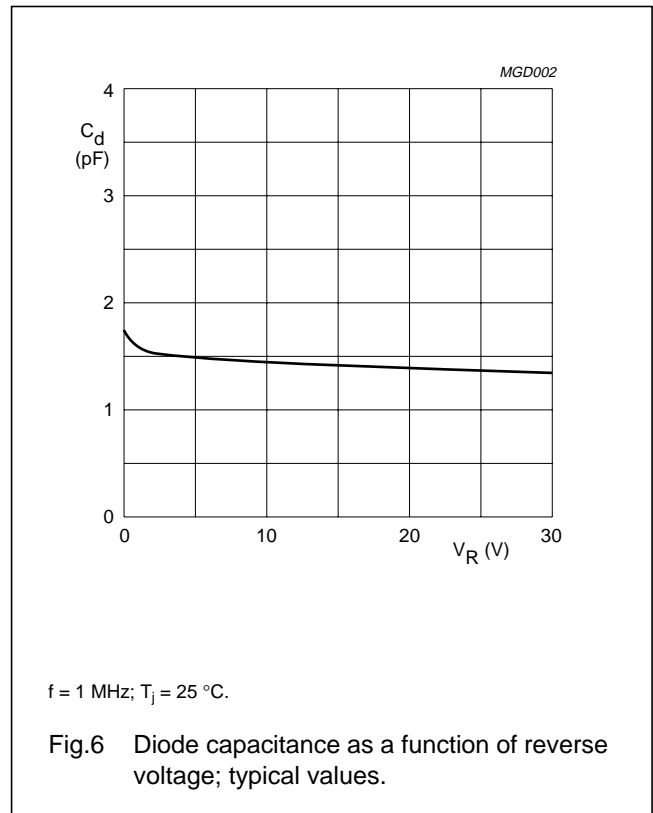
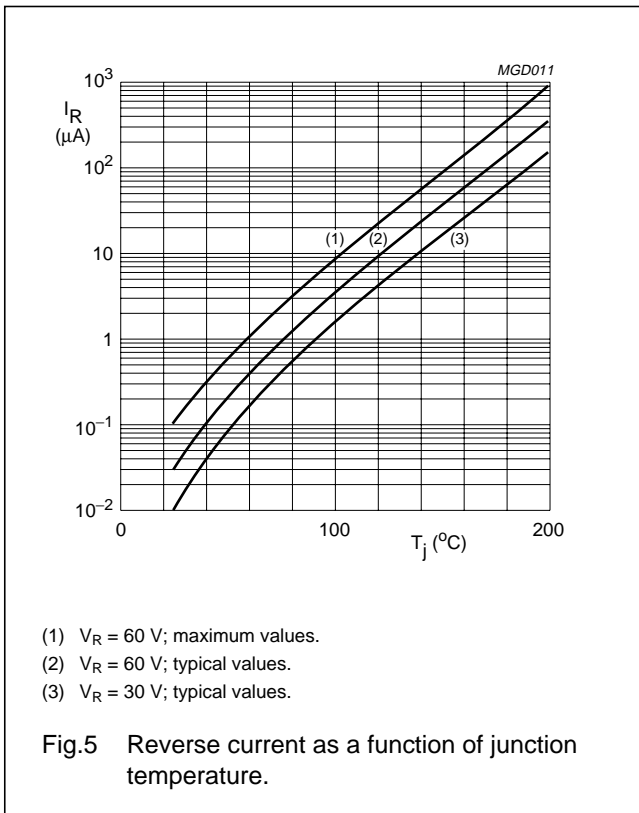
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GRAPHICAL DATA



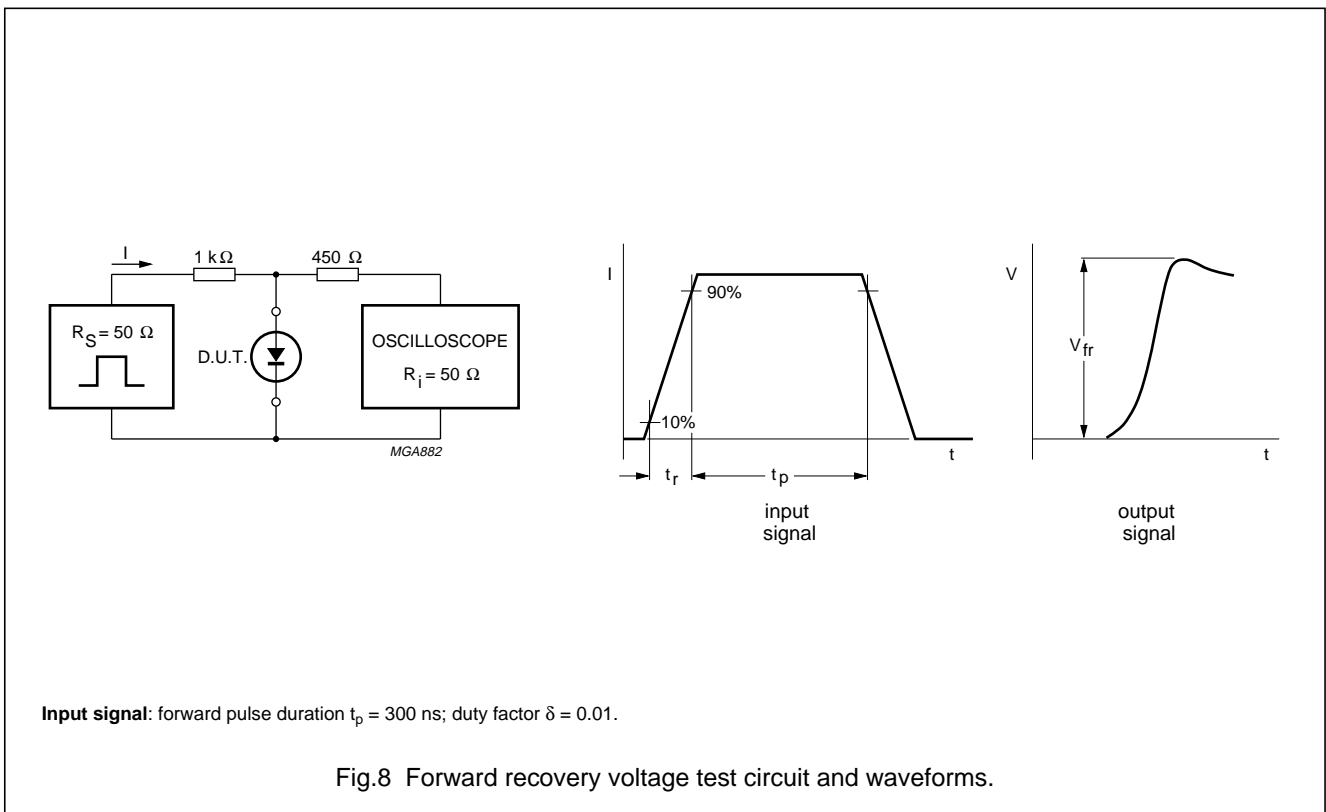
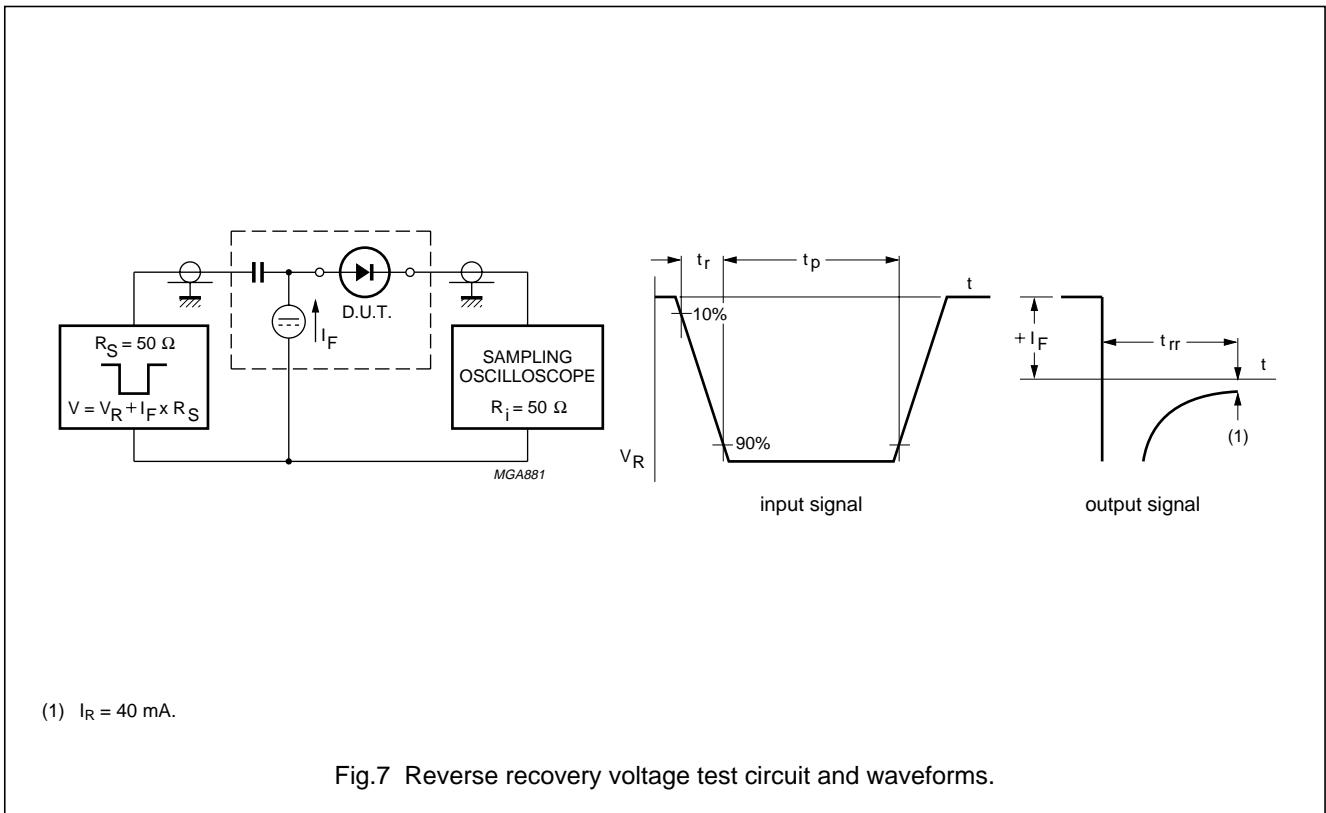
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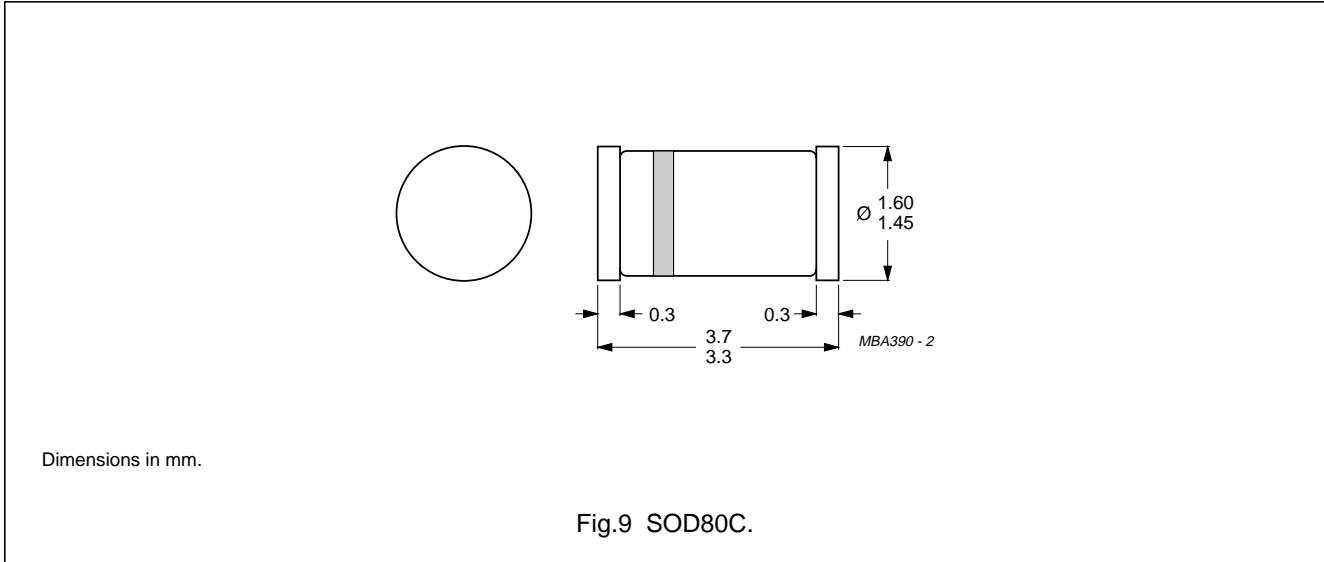
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PACKAGE OUTLINE



DEFINITIONS

| | |
|---|---|
| Data Sheet Status | |
| Objective specification | This data sheet contains target or goal specifications for product development. |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification | This data sheet contains final product specifications. |
| Limiting values | |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | |
| Application information | |
| Where application information is given, it is advisory and does not form part of the specification. | |

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.